NSN 5962-01-259-6501



Memory Microcircuit - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5962-01-259-6501 **Body Length:** 1.490 inches **Body Width:** Between 0.500 inches and 0.610 inches **Body Height:** 0.165 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and programmable and ultraviolet erasable and monolithic **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 17 input **Case Outline Source And Designator:** D-10 mil-m-38510 **Current Rating Per Characteristic:** 50.00 milliamperes forward current, nonrepetitive, peak total value minor **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 0.6 volts total supply and 6.3 volts total supply **Time Rating Per Chacteristic:** 300.00 nanoseconds propagation delay time, low to high level output and 300.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Prom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

28 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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NSN 5962-01-259-6501

Memory Microcircuit - Page 2 of 2



Demilitarization:

No

Fiig:

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